# micro PANAT® HAMAMATSU

MICRO PMT ASSEMBLY MICRO PMT MODULES MICRO PMT PHOTON COUNTING HEAD



# World's smallest and lightest photomultiplier tube\* **Micro PMT**

\* By our research (as of December 2015)

#### Easv to mass produce

Micro PMT can be produced in high volume while still maintaining high reliability and performance. What makes this possible is overall integrated usage of our in-house advanced technologies for MEMS (micro-electro-mechanical systems), semiconductor manufacturing, electron trajectory design, vacuum sealed packaging, and va-

cuum processing.

# Tiny dimensions

Micro PMT has a three-layer structure where a silicon substrate is sandwiched between two glass substrates. Utilizing only three components gives tiny dimensions impossible up until now.

### Customizing support

Feel free to consult with us on customizing to match customer usage conditions and environments.

# **High shock**

Micro PMT devices offer strong shock resistance since anodic bonding by MEMS technology is utilized to join the silicon substrate to the glass substrates. This high cushioning or shock resistance makes them ideal for developing high-performance, hand-held testing and analysis devices.

# **High sensitivity** and fast response

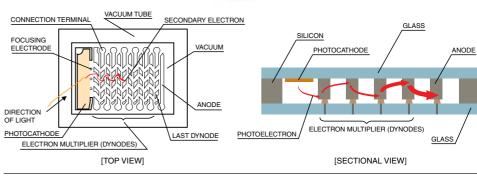
Micro PMT utilizes the same high precision structure for electrode arrangement as conventional PMTs and so provides the high sensitivity and fast response needed from a PMT.

#### Full-scale Micro PMT image!



Micro PMT works on the same vacuum tube technology and principle as conventional PMTs and so can deliver the same performance as conventional PMT yet in a compact and lightweight unit.

#### Micro PMT internal structure



# What is a PMT (photomultiplier tube)?

The PMT is a photosensor delivering superb high sensitivity and response speed compared with other types of photosensors. The PMT makes use of the secondary emission effect for electron multiplication and so achieves extremely high sensitivity and low noise compared to other photosensors currently in use to measure UV light, visible light, and near-infrared light. These features allow the PMT to be used in a broad range of applications including high-performance medical equipment and environmental monitors, etc.

# Medical care

Medical diagnosis in the home or at the bedside

Bringing high-tech closer to the patient via compact and portable medical devices

Tests and inspections normally held in examination rooms or labs can now be made in emergency rooms or small clinics by using the advantages offered by Micro PMT. Performing sophisticated exams in the home could also allow detecting major diseases while still in their early stage. This means the Micro PMT could prove ideal not only for early stage disease diagnosis but also daily health care management.



Making environmental pollution measurements on an individual or regional scale

#### Measurements under various environments and any type of location

Micro PMT also proves ideal as a photosensor for environmental monitoring tasks. Environmental problems including abnormal weather phenomenon and wide-scale natural disasters are recently occurring at places all around the world. If compact measurement devices were readily available, then environmental phenomena could be quickly detected at diverse locations to keep damage and losses to a be minimum.

# **PMT® PRODUCT CONFIGURATION**

#### MICRO PMT ASSEMBLY Type No. Spectral response **MICRO PMT** H12400-00-01 300 nm to 650 nm **VOLTAGE DIVIDER CIRCUIT** H12400-01-01 300 nm to 850 nm compact type \* Suitable high voltage power supply is detailed in last page MICRO PMT MODULES Type No. Spectral response H12402 300 nm to 650 nm **MICRO PMT** H12402-01 300 nm to 850 nm **VOLTAGE DIVIDER CIRCUIT** flat type **HIGH-VOLTAGE** Type No. Spectral response POWER SUPPLY CIRCUIT H12403 300 nm to 650 nm H12403-01 300 nm to 850 nm vertical type

#### ● MICRO PMT PHOTON COUNTING HEAD

MICRO PMT + VOLTAGE DIVIDER CIRCUIT HIGH-VOLTAGE POWER SUPPLY CIRCUIT + PHOTON COUNTING CIRCUIT



Type No.	Spectral response			
H12406	300 nm to 650 nm			
H12406-01	300 nm to 850 nm			

# **MICRO PMT ASSEMBLY** H12400 SERIES

The H12400 series is a high sensitivity photosensor that combines a Micro PMT with a voltage divider circuit. The H12400 series can be installed even in narrow spaces due to its small size.



### SPECIFICATIONS

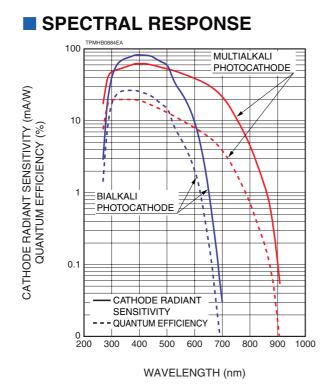
SPECI	FICATION	5				(at +25 °
	Param	neter	H12400-00-01	H12400-01-01	Unit	
Spectral respon	nse		300 to 650	300 to 850	nm	
Peak sensitivity	/ wavelength			420		nm
Photocathode	Material			Bialkali	Multialkali	—
FIIOlocaliloue	Effective area			3(X) × 1(Y)		mm
Window materi	al			Borosilicate glass		—
Dynode numbe	er of stages			1	12	—
Maximum	Supply voltage Between anode and cathode		d cathode	-1	150	V
	Divider current			1	26	μA
ratings	Average output s	signal current			5	μA
	Luminous sensitivity		Min.	50	100	·· A //m
			Тур.	80	200	μA/Im
Cathode	Blue sensitivity index		Тур.	8.0	_	_
	Red / White ratio		Тур.	_	0.2	_
	Radiant sensitivity <sup>①</sup> T		Тур.	80	62	mA/W
	Luminous sensitivity Min.		Min.	30	15	A/Im
			Тур.	160	70	A/Im
	Radiant sensitivity <sup>①</sup>		Тур.	1.6 × 10⁵	2.1 × 10 <sup>4</sup>	A/W
Anode <sup>②</sup>	Dark current <sup>3</sup>		Тур.	0.3		nA
			Max.	3		
	Time response	Rise time	Тур.	1	.2	
		Transit time	Тур.	8	3.0	ns
		T.T.S. <sup>④</sup>	Тур.	1	.3	
Gain <sup>®</sup> Typ.			Тур.	$2 \times 10^{6}$	3.5 × 10 <sup>5</sup>	_
Operating ambient temperature				+5 to +50		°C
Storage temperature				-20 to +50		°C
Weight				1	11	g

1 Measured at the peak sensitivity wavelength

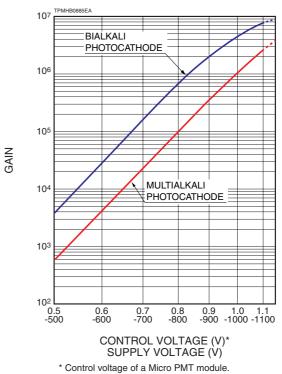
②Supply Voltage: -900 V

③After 30 minutes storage in darkness

(4)T.T.S.=Transit Time Spread (FWHM)



GAIN



**MICRO PMT MODULE** H12402/H12403 SERIES

The H12402/H12403 series are high sensitivity photosensor modules that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit. These modules can be easily operated with a low voltage supply.



▲Left: H12403 series Right: H12402 series

#### PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12402 / H12403	300 nm to 650 nm	Bialkali	for visible range
H12402-01 / H12403-01	300 nm to 850 nm	Multialkali	for visible to near IR range

## SPECIFICATIONS

SPEC	IFICATIONS				(at +25
Parameter			H12402 / H12403	H12402-01 / H12403-01	Unit
Input voltage			+4.5	V	
Maximum inp	ut voltage		4	-5.5	V
Maximum inp	ut current 1			20	mA
Maximum ave	erage output signal current <sup>②</sup>			μΑ	
Maximum cor	ntrol voltage		+1.15		V
Recommende	ed control voltage adjustment range		+0.5 to +1.0	+0.5 to +1.1	V
Control voltag	je input impedance			1	MΩ
Effective area	L		3(X)	× 1(Y)	mm
Peak sensitivi	ty wavelength		4	420	nm
		Min.	50	100	\ /lm
	Luminous sensitivity	Тур.	80	200	μA/Im
Cathode	Blue sensitivity index	Тур.	8.0	_	_
	Red / White ratio	Тур.	—	0.2	_
	Radiant sensitivity <sup>3</sup>	Тур.	80	62	mA/W
	Luminous sensitivity	Min.	30	15	A/Im
		Тур.	160	70	A/Im
Anode <sup>2</sup>	Radiant sensitivity <sup>3</sup>	Тур.	$1.6  imes 10^5$	2.1 × 10 <sup>4</sup>	A/W
Anode	Dark current <sup>®</sup>	Тур.	0.3		nA
	Dark current ©	Max.	3		
	Time response Rise time	Тур.	1.2		ns
Gain <sup>®</sup>		Тур.	$2.0 imes10^{6}$	$3.5  imes 10^5$	
		Max.	0.3		mV
Settling time <sup>®</sup>		Max.	10		S
Operating ambient temperature <sup>®</sup>			+5 to +50		°C
Storage temperature <sup>⑦</sup>			-20 to +50		°C
Weight Typ.			42 (H12402 series), 52 (H12403 series)		g

①At +5 V input voltage, +0.9 V control voltage, and output current equal to dark current

2+0.9 V control voltage

3 Measured at the peak sensitivity wavelength

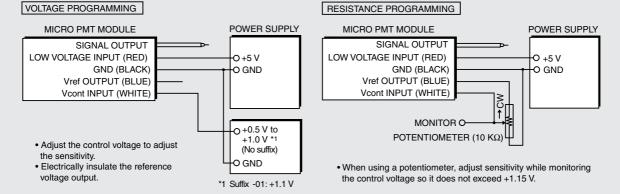
(4) After 30 minutes storage in darkness.

5 Cable RG-174/U, Cable length 450 mm, Load resistance=1 MΩ, Load capacitance=22 pF

(6) The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V.

⑦No condensation

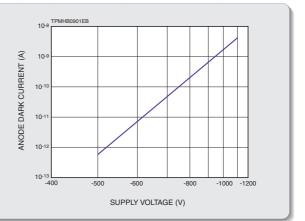
# SENSITIVITY ADJUSTMENT METHOD



# **Characteristics**

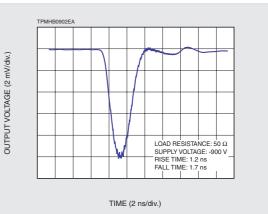
Dark current

A small amount of current is output from a photomultiplier tube even when operated in a completely dark state. This output current is called the anode dark current, and the resulting noise is a critical factor in determining the lower detection limit of photomultiplier tubes. The graph on the right shows typical dark current of a Micro PMT versus the supply voltage.



#### Output waveform

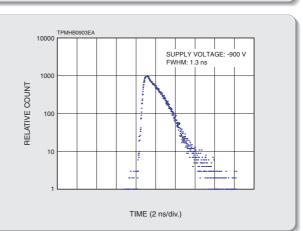
Photomultiplier tubes are photosensors with extremely high speeds. The figure on the right shows an output waveform example of a Micro PMT operating at an anode-tocathode voltage of -900 V, measured with pulsed light (pulse width: 70 ps) that is sufficiently shorter than the response time of the PMT. This anode output pulse has a rise time of 1.2 ns and a fall time of 1.7 ns.



#### **T.T.S.** (transit time spread)

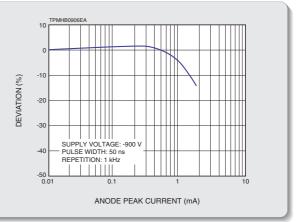
The time interval between the arrival of light at the photocathode and the instant when the anode output pulse reaches its peak amplitude is called the electron transit time.

The T.T.S. (transit time spread) indicates the fluctuations of the electron transit time measured when the photocathode is fully illuminated with single photons, and is defined as the FWHM of the histogram of the fluctuations. A typical T.T.S. of Micro PMT is 1.3 ns.



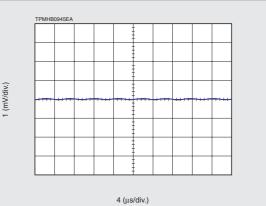
#### Pulse linearity

When an intense light pulse enters the photocathode of a photomultiplier tube, a large current flows in the latter dynode stages and increases the space charge density, causing current saturation. This causes the anode output to deviate from the ideal linearity. The figure below is a typical linearity of a Micro PMT versus light pulse, showing a deviation of approximately 5 % at an anode peak current of 1 mA.



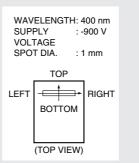
#### Ripple noise

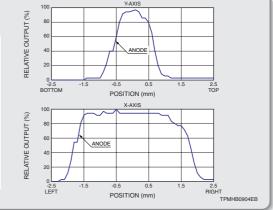
The oscillator circuit used in high-voltage power supplies in photomultiplier tube modules induces noise into the signal input due to oscillation. This induction noise is referred to as ripple. The ripple can be observed on an oscilloscope along the baseline in a low voltage range by feeding the output signal to the oscilloscope input while no light is incident on the modules. For example, under conditions where the load resistance is 1 M $\Omega$  and the load capacitance is 22 pF, you will see a signal with an output near 200  $\mu$ V and a frequency of approximately 220 kHz.



#### Uniformity

This uniformity is the variation of sensitivity with respect to the incident light position on the photocathode. The figure on the right shows an example of anode output measured by scanning a light spot of 1 mm diameter at 400 nm wavelength over the photocathode surface of a Micro PMT at a pitch of 0.1 mm in the X-axis and Y-axis directions. The output indicates relatively good uniformity.



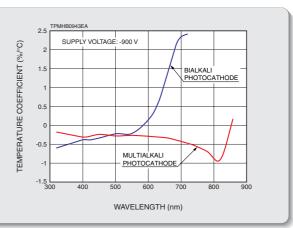


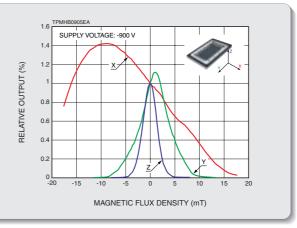
#### Temperature characteristics

The anode sensitivity of photomultiplier tubes is affected by the ambient temperature. Temperature characteristics for anode sensitivity are wavelength-dependent, and the temperature coefficient generally fluctuates from a negative value to a positive value near the long wavelength limit. The figure on the right shows temperature coefficient data of micro PMT with a bialkali photocathode and multialkali photocathode as a function of wavelength. The temperature coefficient for both photocathodes is approximately -0.3 %/°C at a wavelength around 500 nm.

#### Magnetic characteristics

An external magnetic field deviates the photoelectrons traveling in a photomultiplier tube from their normal trajectories, causing a loss of gain. The extent of the loss of gain depends on the direction of the magnetic field. The figure on the right shows how magnetic fields affect the output of a Micro PMT. It is seen that the magnetic field in the Z direction most affects the output. Terrestrial magnetism which is less than 0.1 mT will have almost no effect on the output.





# MICRO PMT PHOTO COUNTING HEAD H12406 SERIES

The H12406 series is a photon counting head that contain a Micro PMT, a highvoltage power supply circuit and a photon counting circuit.

This photon counting head can be easily operated with a low voltage supply.



### SPECIFICATIONS

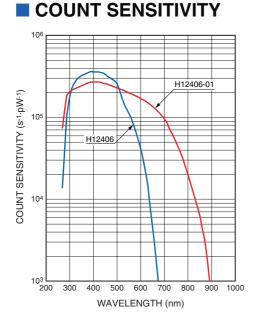
					(at +25 °C
	Parameter		H12406	H12406-01	Unit
Input voltage			+4.75 to +5.25		V
Max. Input voltage			+	6	V
Max. Input current			4	0	mA
Effective area			3×1		mm
Spectral response			300 to 650	300 to 850	nm
Peak sensitivity wa	ve length		420		nm
		300 nm	$1.7  imes 10^5$	$2.1  imes 10^{5}$	
		400 nm	$3.6 imes10^5$	$2.7 imes10^5$	
Count sensitivity	Turp	500 nm	$2.6 imes10^5$	$2.3 imes10^5$	s-1.pW-1
Count sensitivity	ty Typ.	600 nm	$4.3 imes10^4$	$1.7 imes10^5$	5 .pw
		700 nm	$1.4  imes 10^{2}$	$9.6 imes10^4$	
		800 nm	—	$2.1  imes 10^4$	
Count linearity ①			$5.0 imes10^6$		S <sup>-1</sup>
Dark count <sup>2</sup>		Тур.	10	100	
		Max.	50	500	5
Pulse-pair resolutio	n		20		ns
Output pulse width			10		ns
Output pulse height	t	Min.	+2.0		– v
(at load resistance 50 $\Omega$ ) Typ.			+2.2		v
Recommended load	d resistance		50		Ω
Signal output logic			Positive logic		
Excessive light	Excessive light incident	Min.	+3.5		V
detection output <sup>③</sup> Normally Max. +0.5		V			
Operating ambient temperature <sup>(4)</sup>			+5 to +50		°C
Storage temperature ④			-20 to +50		°C
Weight			46		g

1 Random pulse, at 10% count loss

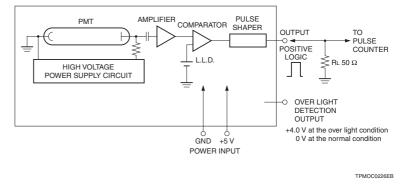
②After 30 minute storage in darkness

3Load resistance 10 k $\Omega$ 

④No condensation



## BLOCK DIAGRAM

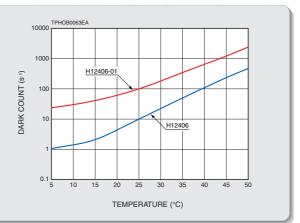


(at +25 °C)

# Characteristics

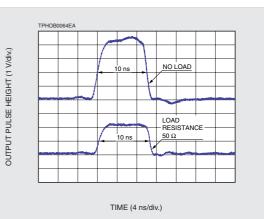
Dark count

Some dark current pulses are generated in a photomultiplier tube during operation even if no light is incident on it. These dark current pulses are amplified by an amplifier and then only those dark pulses with a height exceeding a certain discriminator threshold are output through a pulse shaper. This output, expressed in counts per second (s<sup>-1</sup>), is the dark count and indicates the lower limit of signal detection.



#### Output waveform

Output waveforms are positive logic signals. The figure on the right shows output waveforms measured with and without a load resistance of 50  $\Omega$ . Since photon counting head handles high-speed signals, a 50  $\Omega$  impedance cable is usually connected between a photon counting head and external device, and the input impedance of the external device should also preferably be 50  $\Omega$ .



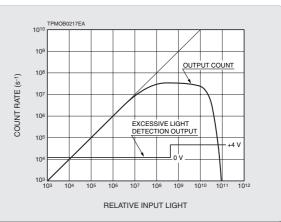
### Count linearity and excessive light detection characteristics

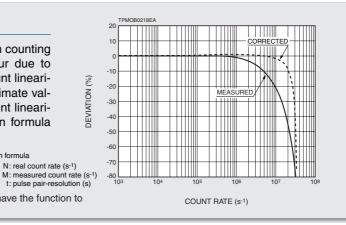
In a random light input event, when the light level increases and exceeds a certain level, the output pulses begin to overlap each other and the count value is no longer proportional to the light level. As the light level further increases causing more pulses to overlap, the number of output pulses gradually saturates and then begins to decrease and eventually reaches 0. Count linearity is specified as the count value at which a 10 % loss occurs in the counted value compared to the theoretical value.

If the incident light level largely exceeds the count linearity, a signal (4.0 V) is output to indicate an excessive light input.

## Count rate correction

When the number of pulses measured by photon counting exceeds 10<sup>6</sup> s<sup>-1</sup>, counting errors begin to occur due to pulse overlap. One method for improving the count linearity utilizes a correction formula to find the approximate values. The graph on the right shows improved count linearity characteristics obtained by using a correction formula to find the approximate values.





\* Micro PMT photon counting head H12406 series do not have the function to automaticlly output a correction value.

Linearity correction formula

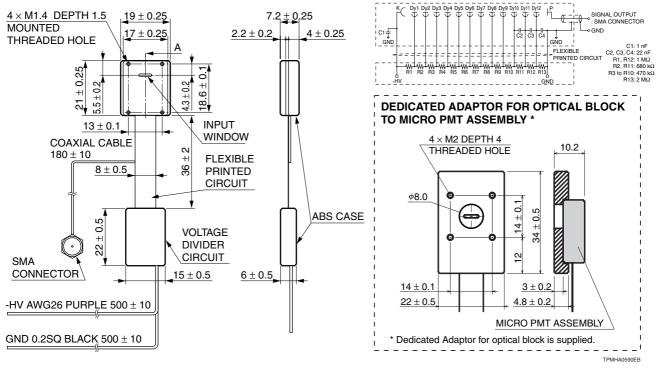
 $N = \frac{M}{1-Mt}$ 

N: real count rate (s-1)

# DIMENSIONAL OUTLINES (Unit: mm)

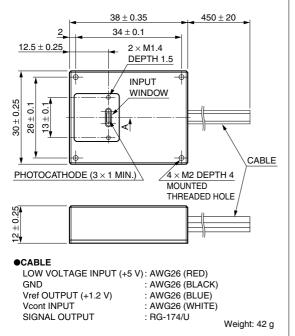
#### MICRO PMT ASSEMBLY

#### ■ H12400 Series



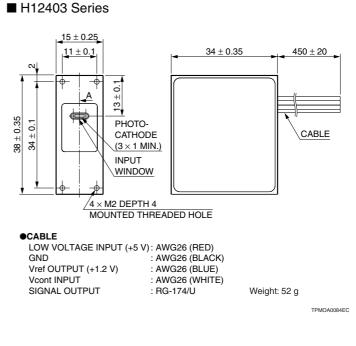
#### **MICRO PMT MODULE**

H12402 Series



TPMOA0083EC

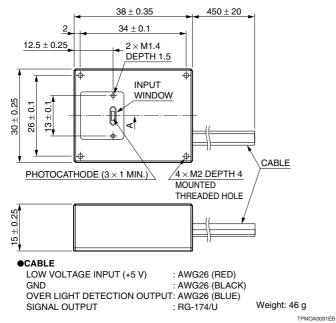
#### MICRO PMT MODULE

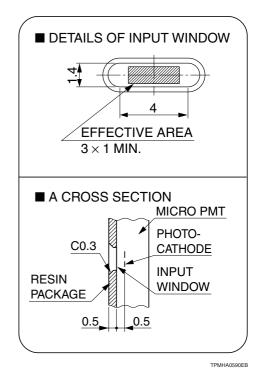


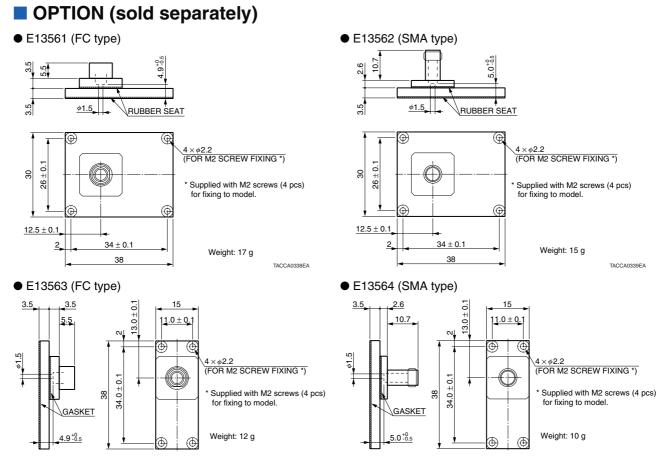


#### **MICRO PMT PHOTON COUNTING HEAD**

■ H12406 Series







\* E13561 and E13562 are the exclusive options for H12402/H12406 series. E13563 and E13564 are the exclusive options for H12403 series.

# Related **Products**



#### HIGH VOLTAGE POWER SUPPLY C10940 SERIES 0.7 W output 1200 V / 0.6 mA

The C10940 series is a high voltage power supply module developed for compact size and high performance. This is designed to mount on a printed circuit making them ideal for use with a H12400 series Micro PMT assembly. Besides high performance and low power consumption, a variety of protective functions are also included.

Protective Functions: Units protected against reversed power input, reversed / excessive controlling voltage input, continuous over loading / short circuit output

Parameter	C10940-03	C10940-03-R2*	C10940-53	C10940-53-R2*	Unit	
Input Voltage		+5 ± 0.5				
Input Current <sup>①</sup>	Тур.		60 (no load), 230 (full load)			mA
Output Voltage		-10 to -1200 +10 to +1200		V		
Output Current	Max.		0.6			mA
Ripple / Noise (p-p) 12	Тур.	50				mV
Operating Ambient Temperature <sup>(1)</sup> / Humid	ity <sup>③</sup>		0 °C to +50 °C	: / Below 80 %	—	
Storage Temperature / Humidity <sup>3</sup>		-20 °C to +60 °C / Below 80 %			—	
Weight	Тур.	8.5			g	
Dimensions (W $\times$ H $\times$ D)			15 × 1	8 × 15		mm
1): At maximum output voltage (2): At maximum	rent ③: No conde	ensation				

\* -R2 type: RS-485 control

POWER SUPPLY FOR PMT MODULE C10709



# The C10709 is a power supply unit designed to operate a PMT module. This unit supplies both drive

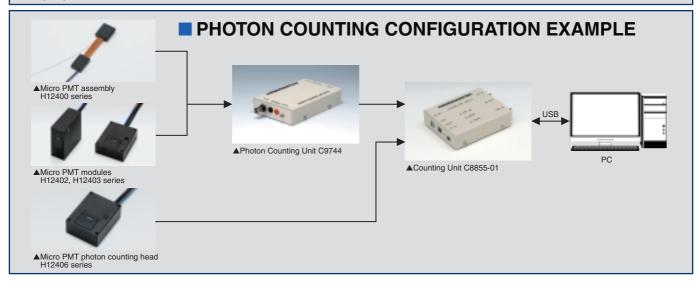
voltage and control voltage, making it ideal for operating the H12402 series and H12403 series Micro PMT modules





### AMPLIFIER UNITS

These amplifier units convert the signal current input from a photomultiplier tube into a voltage output. Please select the desired type with a frequency range and current-to-voltage conversion factor that match your applications.



#### \* <sup>#PMT</sup> is the registered trademark of Hamamatsu Photonics K.K. in Japan, U.S.A., and EU.

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